

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	90	361/437.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 21:29
S1	137	(scr (silicon adj control adj rectifier) thiristor) same (hf (high adj frequency) same insufficient same power same start)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 18:52
S2	139	(scr (silicon adj control adj rectifier) thiristor) same (hf (high adj frequency) same insufficient same power same (start fire))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 18:53
S3	7	(scr (silicon adj control adj rectifier) thiristor) same (hf (high adj frequency)) same insufficient same power same (start fire)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:02
S4	13	(scr (silicon adj control adj rectifier) thiristor) same (hf (high adj frequency)) same insufficient same (start fire)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:12
S5	6	S4 not S3	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:02
S6	19	(scr (silicon adj control adj rectifier) thiristor) same (hf (high adj frequency)) same insufficient same control	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:12
S7	13	(scr (silicon adj control adj rectifier) thiristor) same (hf (high adj frequency)) same insufficient same control not S5 not S4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:13

EAST Search History

S8	32894	power near (hf (high adj frequency))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:20
S9	2	power near (hf (high adj frequency)) near insufficient	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:21
S10	11	power near (hf (high adj frequency)) near3 insufficient	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:23
S11	5	power near7 (hf (high adj frequency)) near7 insufficient near7 (switch\$3 contact\$3 transistor bjt igbt ((nnp npn) NEAR junction) thyristor triac scr (silicon adj control adj rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:27
S12	11	power near13 (hf (high adj frequency)) near13 insufficient near13 (switch\$3 contact\$3 transistor bjt igbt ((nnp npn) NEAR junction) thyristor triac scr (silicon adj control adj rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:38
S13	13	"4779036" "4649414"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:36

EAST Search History

S15	11	power near13 (hf (high adj frequency)) near13 (non-sufficient (non adj sufficient) insufficient) near13 (switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon adj control adj rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:38
S16	19	(power voltage) near13 (hf (high adj frequency)) near13 (non-sufficient (non adj sufficient) insufficient) near13 (switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon adj control adj rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:40
S17	8	S16 not S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:40
S18	20	(power energy voltage) near13 (hf (high adj frequency)) near13 (non-sufficient (non adj sufficient) insufficient) near13 (switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon adj control adj rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:50
S19	9	S18 not S15	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:40

EAST Search History

S20	905	(power energy voltage) same (hf (high adj frequency)) same (non-sufficient (non adj sufficient) insufficient) same (switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon adj control adj rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 19:51
S21	1	wo adj "0250850"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:14
S22	1	WO/0250850	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:14
S23	23	"0250850"	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:14
S24	11009	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near3 (hf h-f hi-fi (high adj frequency) near3 control)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:20
S25	7505	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near2 (hf h-f hi-fi (high adj frequency) near2 control)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:19

EAST Search History

S26	3863	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near (hf h-f hi-fi (high adj frequency) near control)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:20
S27	1709	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near3 (hf h-f hi-fi (high adj frequency)) near3 control	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:20
S28	779	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near2 (hf h-f hi-fi (high adj frequency)) near2 control	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:21
S29	246	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near (hf h-f hi-fi (high adj frequency)) near control	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:21
S30	11	(switch\$3 contact\$3 transistor bjt igbt ((npn pnp) NEAR junction) thyristor triac scr (silicon ADJ control ADJ rectifier) varactor varicon sidac fet jfet mos (field adj effect adj transistor) (Metal-Oxide adj Semiconductor) (Metal adj Oxide adj Semiconductor)) near (hf h-f hi-fi (high adj frequency)) near control and insufficient	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2006/08/04 20:21